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Assistant Commissioner for Patents
Washington, D.C. 20231

PATENT
Attorney Docket No.: 18865-000800US
Client Reference No.: 17732-8026

On April 23, 2001

TOWNSEND and TOWNSEND and CREW LLP

By: Sherry Barton

#13/Amend B
Amended
5/2/01

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

MO, B.

Application No.: 09/282,274

Filed: March 31, 1999

For: A TRENCH TRANSISTOR WITH
A SELF-ALIGNED SOURCE

Examiner: S. Hu

Art Unit: 2811

AMENDMENT

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Assistant Commissioner for Patents
Washington, D.C. 20231

Sir:

In response to the Office Action mailed February 23, 2001, please amend the above-identified application as follows:

IN THE CLAIMS:

Please amend claim 1 as follows:

1. (Twice Amended) A trench transistor comprising:
- a substrate having a surface;
 - a trench extending a selected depth into the substrate from the surface, the trench having a sidewall;
 - a gate structure at least partially within the trench;
 - a source contact region extending a selected distance into the substrate from the surface; and
 - a source region self-aligned to the gate,

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05/02/2001 30.00 CH

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